

Supporting Information

Ionization of Hole-Transporting Materials as a Method for Improving the Photovoltaic Performance of Perovskite Solar Cells

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Supplementary Figures

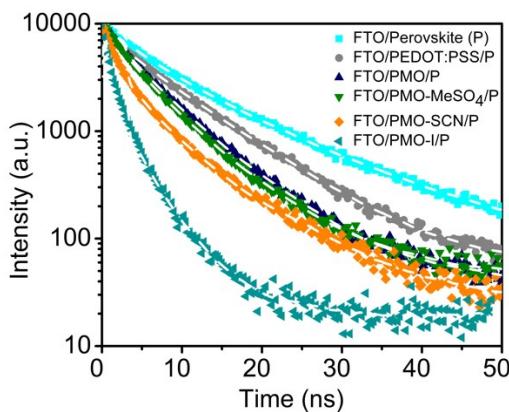


Figure S1. Time-resolved photoluminescence for perovskites and perovskites/HTM interface.

Table S1. The detailed parameters of PL obtained by fitting the TRPL of **PEDOT:PSS**, **PMO**, **PMO-MeSO₄**, **PMO-SCN** and **PMO-I**.

HTM	A ₁	τ ₁	A ₂	τ ₂	τ Avg
FTO	6827.6	6.0261	3025.2	17.46	9.539
PEDOT:PSS	1976.6	1.7197	7534.3	8.3250	6.952
PMO	4996.3	3.3416	5037.3	7.3400	5.349
PMO-MeSO₄	5765.80	3.2037	4246.2	7.4159	4.990
PMO-SCN	6472.00	1.5049	3648.3	6.7962	3.412
PMO-I	5765.49	0.6980	3985.9	2.6811	1.509

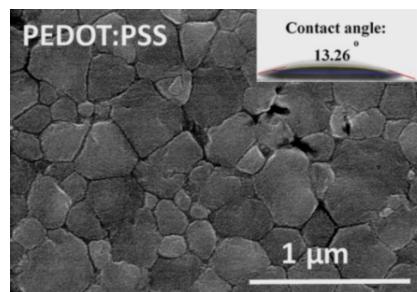


Figure S2. Scanning electron microscopy top-view image, with inset water contact angle, of **PEDOT:PSS** film.

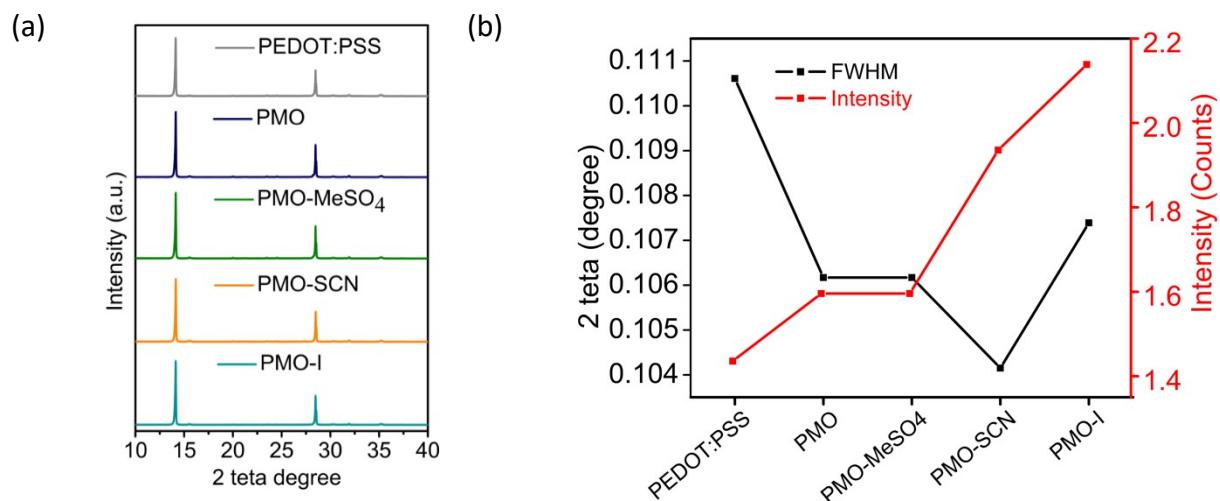


Figure S3. (a) X-ray diffraction of perovskite films atop of different HTM films. (b) Fitted results of X-ray diffraction ratio.

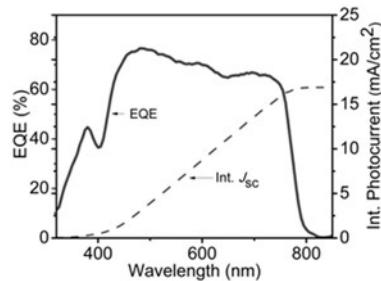


Figure S4. EQE spectra with integrated J_{sc} of the PSCs with **PEDOT:PSS**.

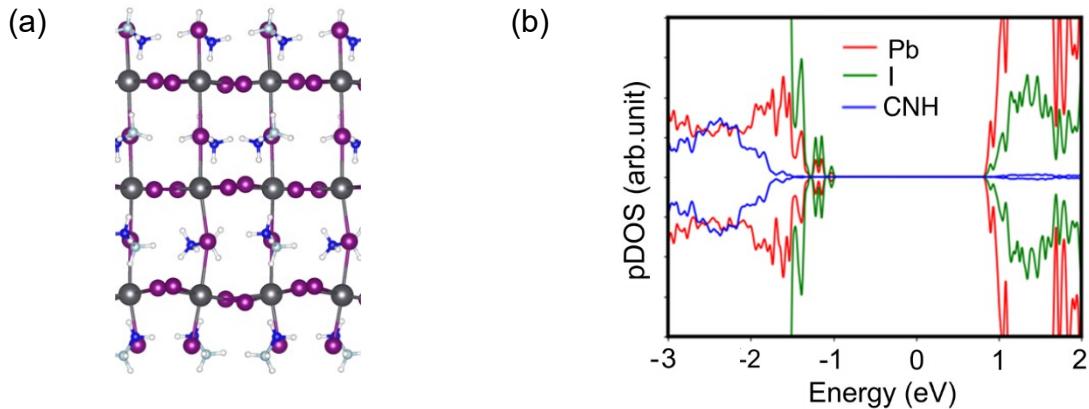


Figure S5. The (a) optimized structure and (b) partial density of states (pDOS) of pristine MAPbI₃ slab. The slab has four layers of PbI. The pDOS depicts that there is no surface induced state(s) appear inside the bandgap of MAPbI₃.

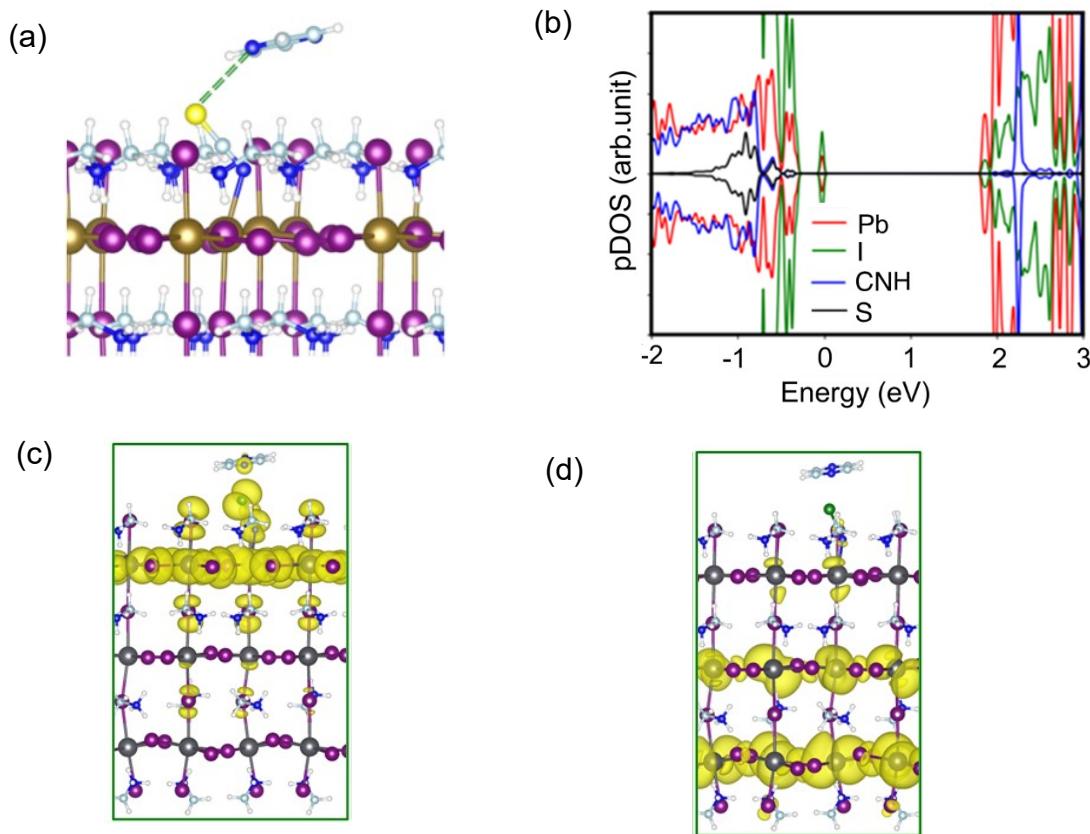
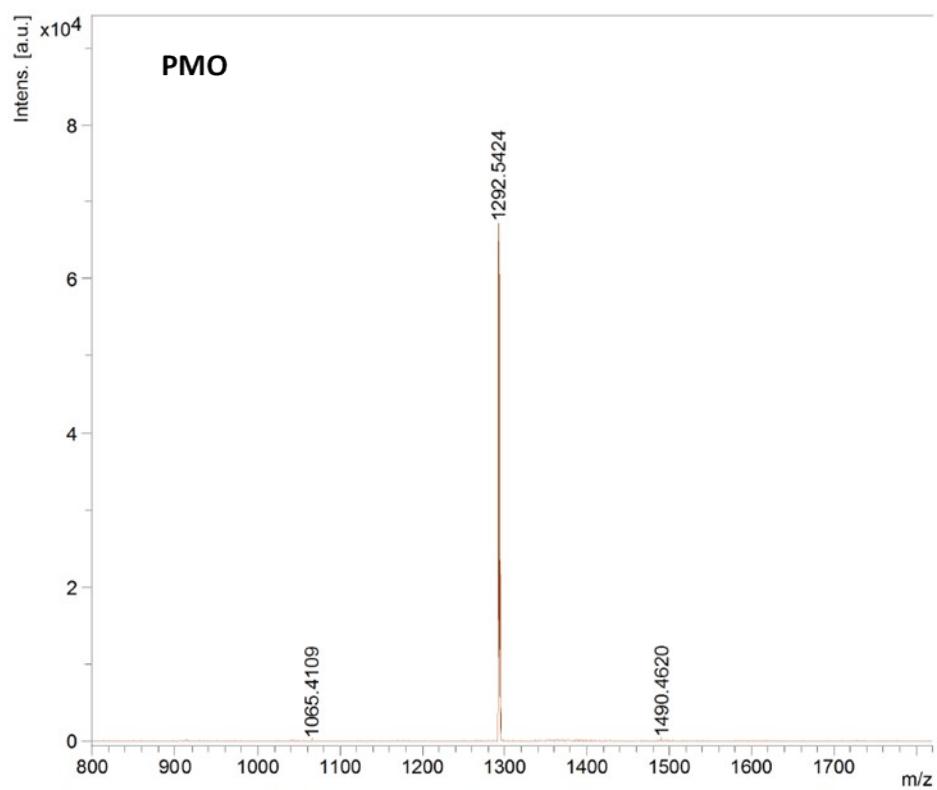
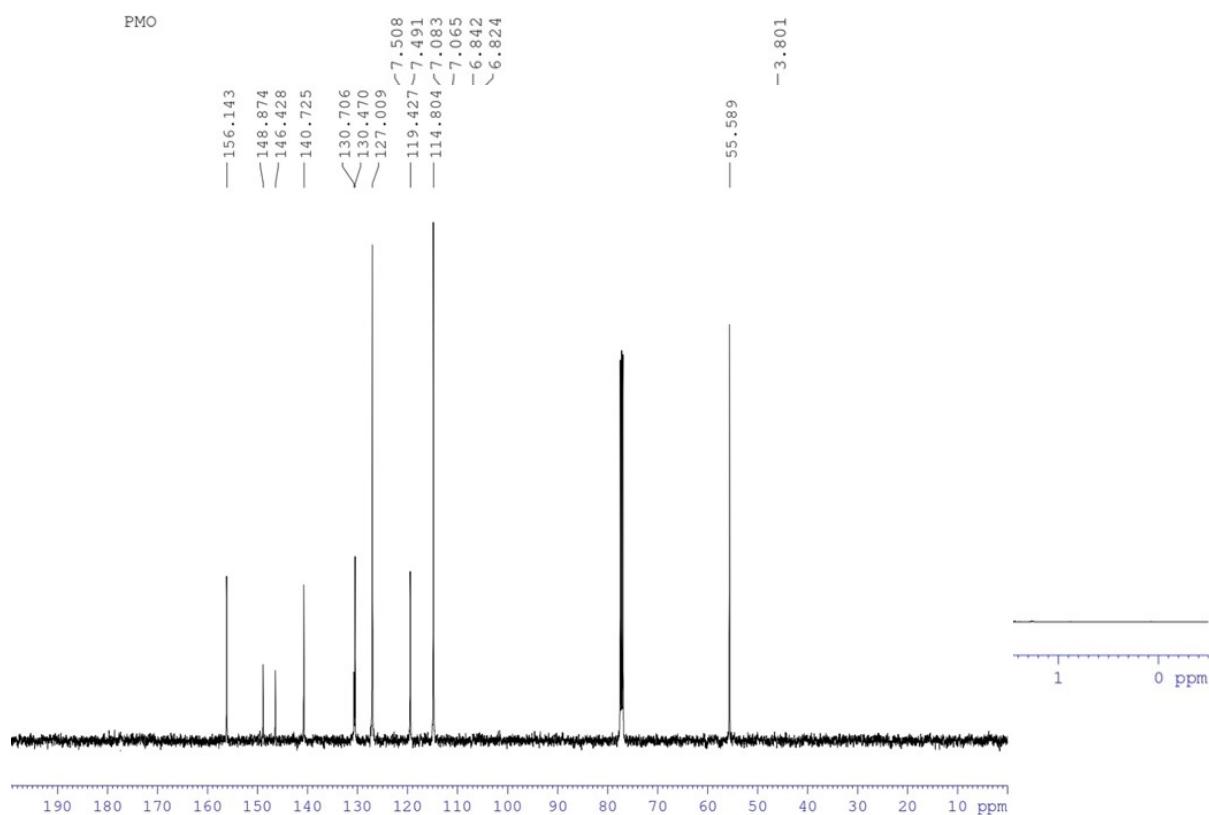
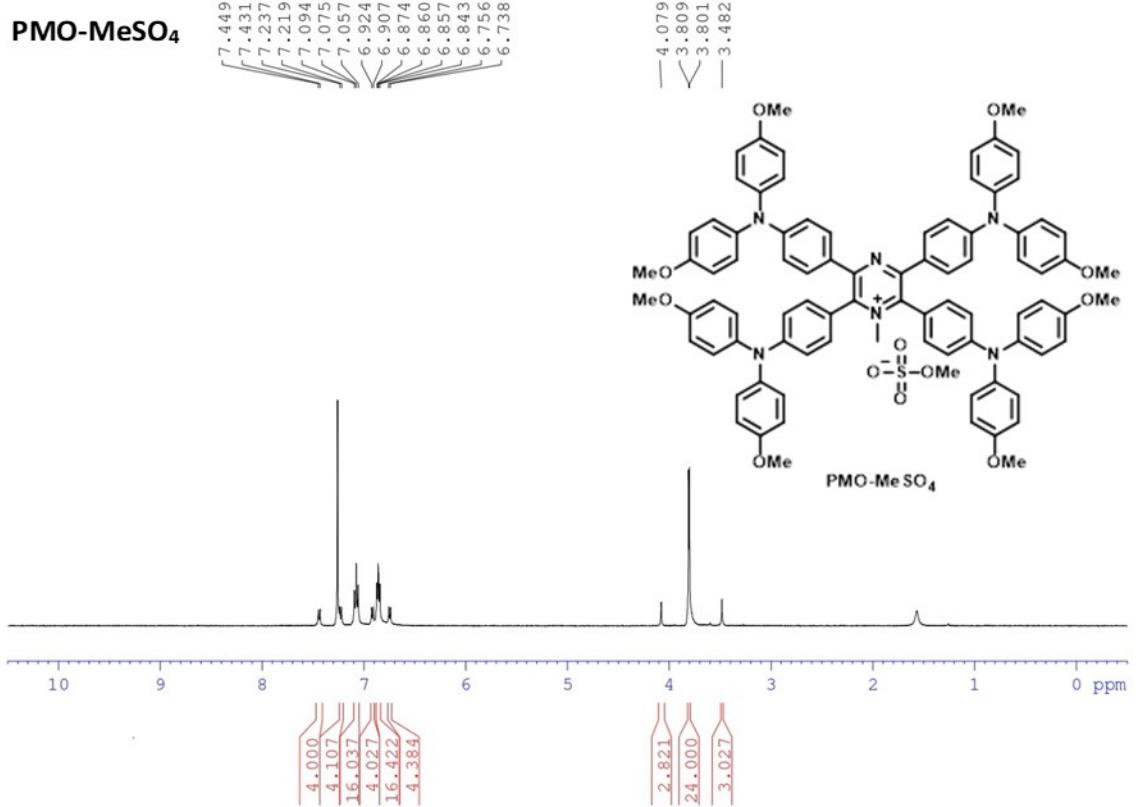


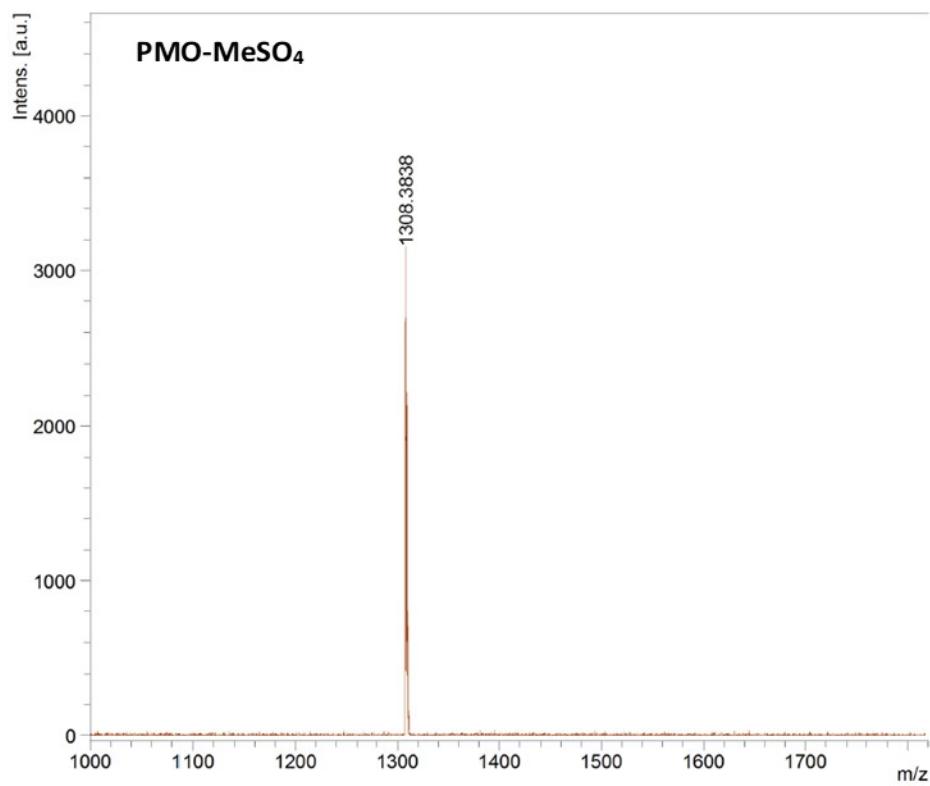
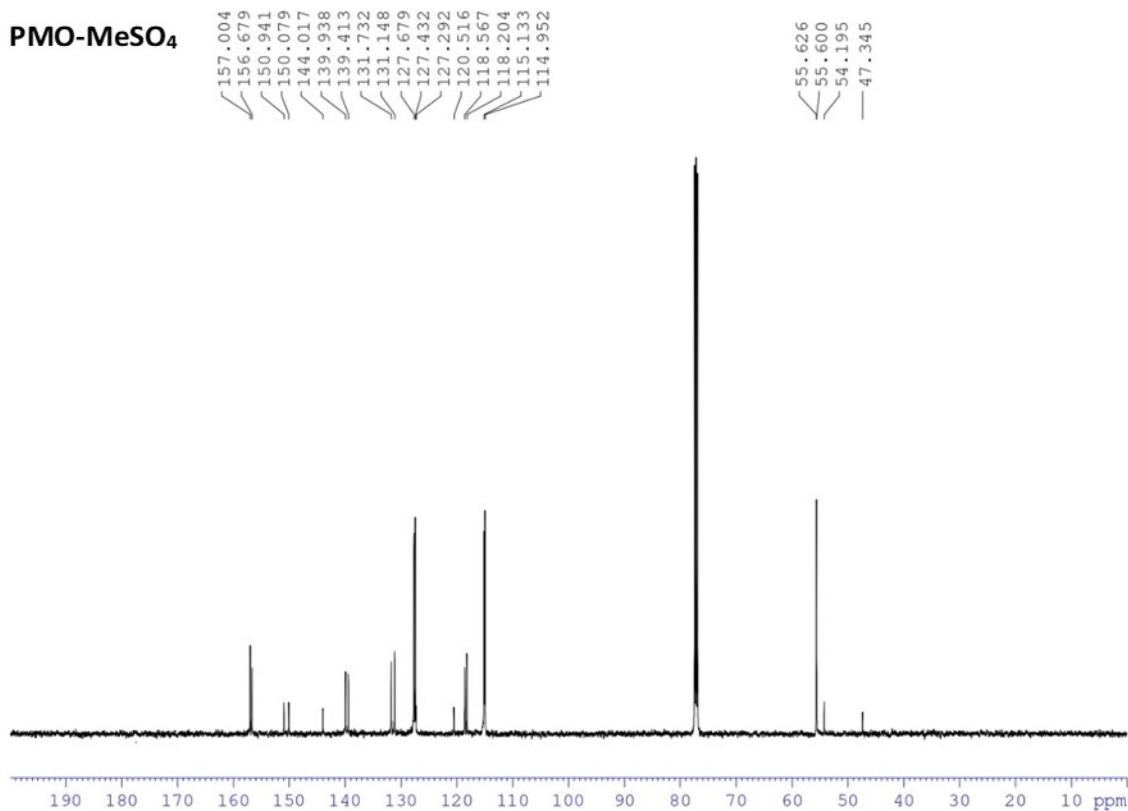
Figure S6. The (a) optimized structure and (b) partial density of states (pDOS) of PMO-SCN passivated MAPbI₃ slab. The charge densities of the (c) VBM and (d) CBM. The wavefunctions of the band edge states show significant delocalization. Key: Sulphur (green).

H¹ and C¹³ NMR

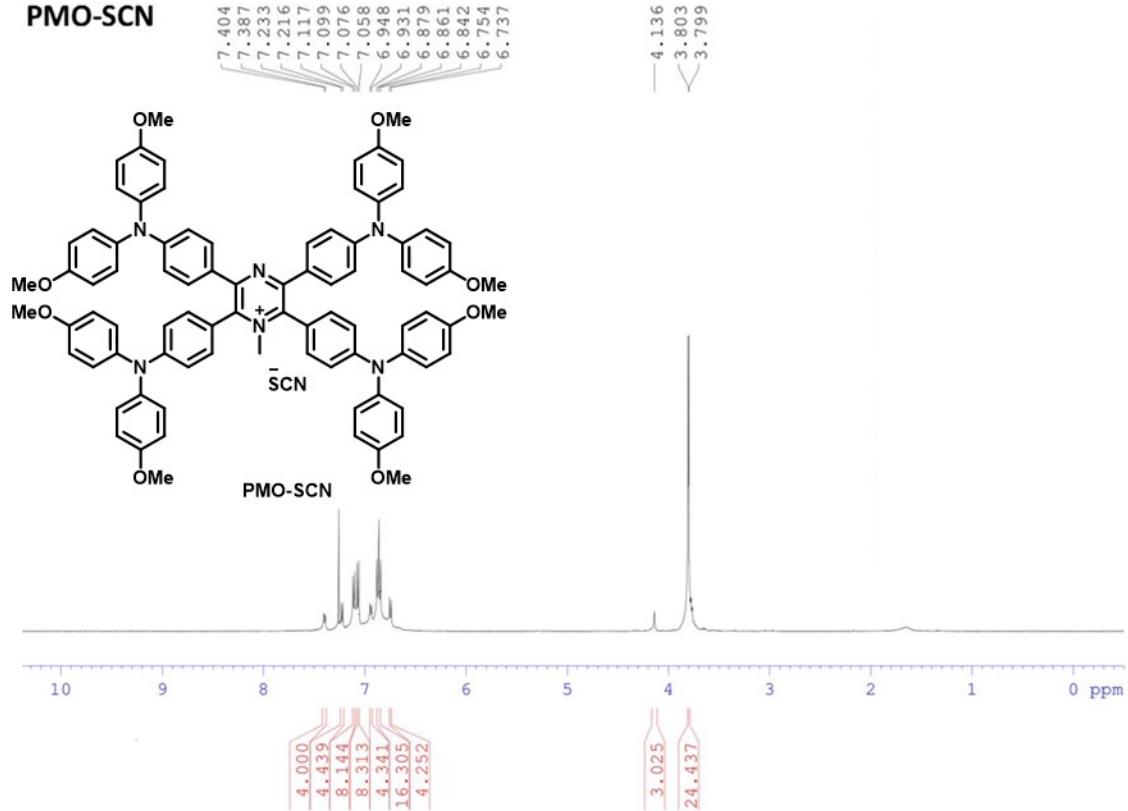




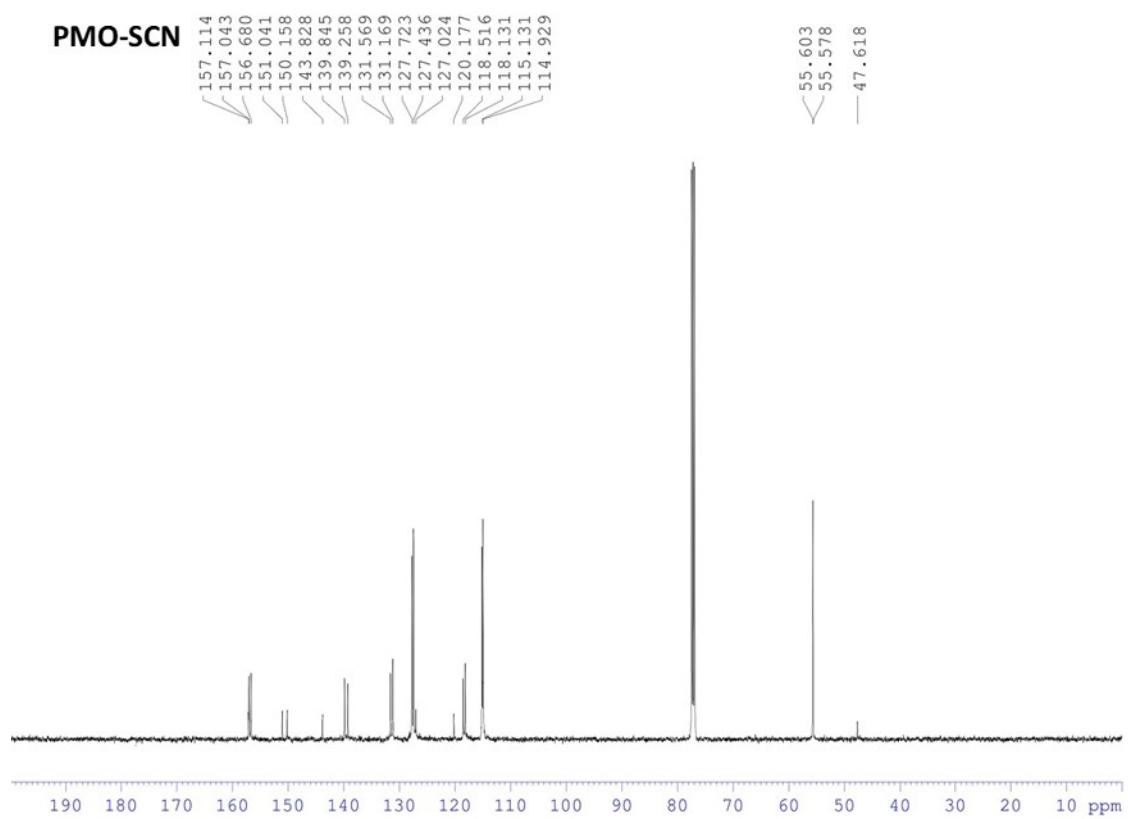
PMO-MeSO₄

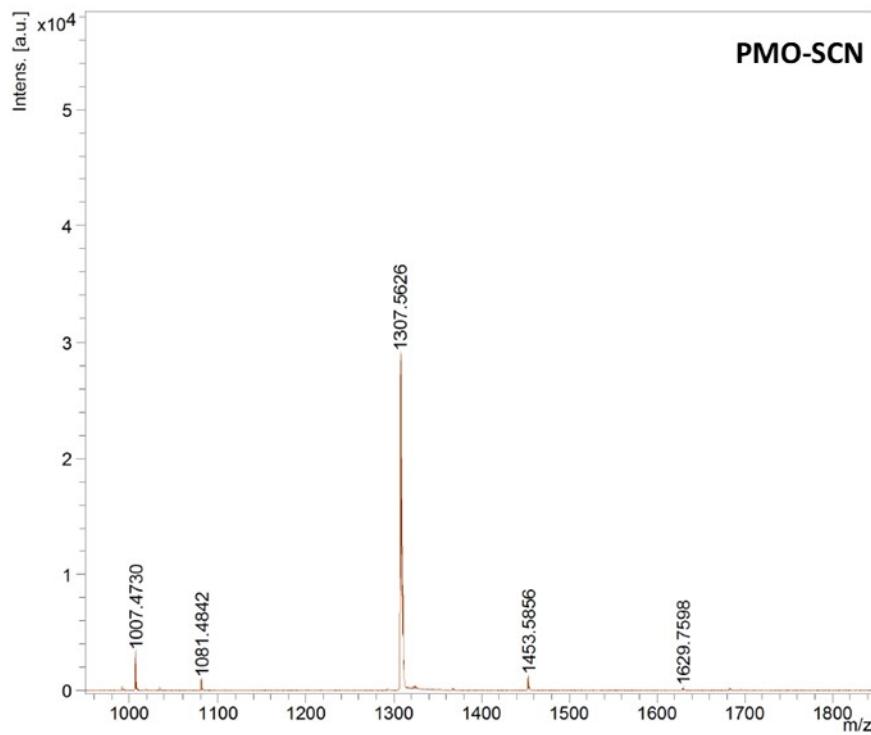


PMO-SCN

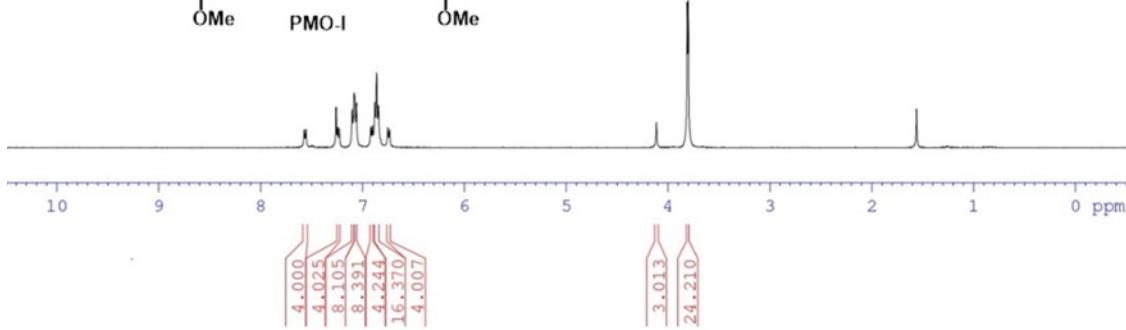
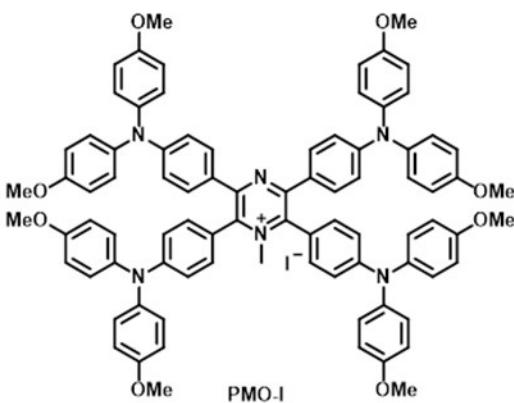
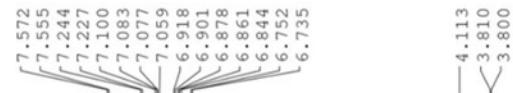


PMO-SCN





PMO-I



PMO-I

